

Absolute Maximum Ratings

Storage Temperature	-65°C to 150°C
V _{CC}	-0.3V to 30V
V _{CC} Peak Transient Voltage (load dump = 26V w/series 10Ω resistor)	40V
Input Voltage Range (at any input)	-0.3V to 10V
Maximum Junction Temperature	150°C
Lead Temperature Soldering	
Wave Solder (through hole styles only)	10 sec. max, 260°C peak
ESD Capability (Human Body Model)	2kV

Electrical Characteristics: 4V ≤ V_{CC} ≤ 26V, -40°C < T_A < 125°C, (unless otherwise specified)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
■ V_{CC} Supply					
Operating Current Supply	7V ≤ V _{CC} ≤ 18V		5	10	mA
	4V ≤ V _{CC} < 7V, 18V < V _{CC} ≤ 26V			15	mA
Quiescent Current	V _{CC} = 12V		170	275	μA
Overshoot Shutdown		26.5		29	V
■ Control (CTL)					
Control Input Current	CTL = 0V to 5V	-2	0.1	2	μA
Sleep Mode Threshold		8%	10%	12%	V _{REG}
Sleep Mode Hysteresis	7V ≤ V _{CC} ≤ 26V	50	100	150	mV
	4V ≤ V _{CC} < 7V	10		150	mV
■ Current Sense					
Differential Voltage Sense	7V ≤ V _{CC} ≤ 18V				
	I _{ADJ} = 1V and R _{CS1} = 51Ω	18		34	mV
	I _{ADJ} = 4V and R _{CS1} = 51Ω	104		125	mV
	4V ≤ V _{CC} < 7V				
	I _{ADJ} = 1V and R _{CS1} = 51Ω	15		39	mV
I _{ADJ} Input Current	18V < V _{CC} ≤ 26V				
	I _{ADJ} = 1V and R _{CS1} = 51Ω	15		39	mV
	I _{ADJ} = 4V and R _{CS1} = 51Ω	102		130	mV
	4V ≤ V _{CC} ≤ 26V	-2	0.3	2	μA
	I _{ADJ} = 0V to 5V				
■ Linear Regulator					
Output Voltage, V _{REG}	V _{CC} = 4V	2.0			V
	V _{CC} = 13.2V	4.85		5.15	V
	V _{CC} = 26V	4.85		5.20	V
■ Inhibit					
Inhibit Threshold		40%	50%	60%	V _{REG}
Inhibit Hysteresis	4V ≤ V _{CC} ≤ 7V	100		500	mV
	7V ≤ V _{CC} ≤ 26V	150	325	500	mV
■ External Drive (OUTPUT)					
Output Frequency	4V ≤ V _{CC} < 7V				
	R _{OSC} = 93.1kΩ, C _{OSC} = 470pF	10		25	kHz
	7V ≤ V _{CC} ≤ 18V,				
R _{OSC} = 93.1kΩ, C _{OSC} = 470pF	17	20	23	kHz	
18V < V _{CC} ≤ 26V					
R _{OSC} = 93.1kΩ, C _{OSC} = 470pF	17	20	25	kHz	

Electrical Characteristics: $4V \leq V_{CC} \leq 26V$, $-40^{\circ}C < T_A = 125^{\circ}C$, (unless otherwise specified)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
External Drive (OUTPUT): continued					
Voltage to Duty Cycle Conversion	$4V \leq V_{CC} < 7V$				
	$V_{CC} = 13V$, CTL = 1V	65		75	%
	$V_{CC} = 13V$, CTL = 2V	100			%
	$7V \leq V_{CC} \leq 18V$				
	$V_{CC} = 13V$, CTL = 30% V_{REG}	28.3		36.3	%
	$V_{CC} = 13V$, CTL = 55.8% V_{REG}	56.0		64.0	%
	$18V < V_{CC} \leq 26V$				
Output Rise Time	$V_{CC} = 13V$, CTL = 1.5V	11.8		21.8	%
	$V_{CC} = 13V$, CTL = 3.5V	34.2		44.2	%
Output Rise Time	$4V \leq V_{CC} \leq 26V$ $R_{GATE} = 6\Omega$, $C_{GATE} = 5nF$.25	1	μs
Output Fall Time	$4V \leq V_{CC} \leq 26V$ $R_{GATE} = 6\Omega$, $C_{GATE} = 5nF$.30	1	μs
Output Sink Current	$4V \leq V_{CC} < 7V$ $R_{GATE} = 6\Omega$, $C_{GATE} = 5nF$		150		mA
	$7V \leq V_{CC} \leq 26V$ $R_{GATE} = 6\Omega$, $C_{GATE} = 5nF$		300		mA
Output Source Current	$4V \leq V_{CC} < 7V$ $R_{GATE} = 6\Omega$, $C_{GATE} = 5nF$		150		mA
	$7V \leq V_{CC} \leq 26V$ $R_{GATE} = 6\Omega$, $C_{GATE} = 5nF$		300		mA
Output High Voltage	$I_{OUT} = 1mA$	$V_{BOOST} - 1.7$			V
Output Low Voltage	$I_{OUT} = -1mA$			1.3	V

Charge Pump (DRV)

Boost Voltage	$V_{CC} + 6.4$			V
---------------	----------------	--	--	---

Package Lead Description

PACKAGE LEAD #	LEAD SYMBOL	FUNCTION
16 Lead PDIP		
1	OUTPUT	MOSFET gate drive
2	BOOST	Boost voltage
3	FLT	Fault time out capacitor
4	R _{OSC}	Oscillator resistor
5	C _{OSC}	Oscillator capacitor
6	CTL	Pulse width control input
7	PGnd	Power ground for on chip clamp
8	V _{CC}	Positive power supply input
9	V _{REG}	5V linear regulator
10	SNI	Sense inductor current
11	PMP	Collector of boost power transistor
12	I _{SENSE-}	Current sense minus
13	I _{SENSE+}	Current sense plus
14	I _{ADJ}	Current limit adjust
15	INH	Output Inhibit
16	Gnd	Ground

Theory Of Operation

Oscillator

The IC sets up a constant frequency triangle wave at the C_{OSC} lead whose frequency is related to the external components R_{OSC} and C_{OSC} by the following equation:

$$\text{Frequency} = \frac{0.83}{R_{OSC} \times C_{OSC}}$$

The peak and valley of the triangle wave are proportional to V_{CC} by the following:

$$V_{VALLEY} = 0.1 \times V_{CC}$$

$$V_{PEAK} = 0.7 \times V_{CC}$$

This is required to make the voltage compensation function properly. In order to keep the frequency of the oscillator constant the current that charges C_{OSC} must also vary with supply. R_{OSC} sets up the current which charges C_{OSC} . The voltage across R_{OSC} is 50% of V_{CC} and therefore:

$$I_{ROSC} = 0.5 \times \frac{V_{CC}}{R_{OSC}}$$

I_{ROSC} is multiplied by (2) internally and transferred to the C_{OSC} lead. Therefore:

$$I_{COSC} = \pm \frac{V_{CC}}{R_{OSC}}$$

The period of the oscillator is:

$$T = 2C_{OSC} \times \frac{V_{PEAK} - V_{VALLEY}}{I_{COSC}}$$

The R_{OSC} and C_{OSC} components can be varied to create frequencies over the range of 15Hz to 25kHz. With the suggested values of 93.1k Ω and 470pF for R_{OSC} and C_{OSC} , the nominal frequency will be approximately 20 kHz. I_{ROSC} at $V_{CC} = 14V$, will be 66.7 μA . I_{ROSC} should not change over a more than 2:1 ratio and therefore C_{OSC} should be changed to adjust the oscillator frequency.

Voltage Duty Cycle Conversion

The IC translates an input voltage at the CTL lead into a duty cycle at the OUTPUT lead. The transfer function incorporates Cherry Semiconductor's patented Voltage Compensation method to keep the average voltage and current across the load constant regardless of fluctuations in the supply voltage. The duty cycle is varied based upon the input voltage and supply voltage by the following equation:

$$\text{Duty Cycle} = 100\% \times \frac{2.8 \times V_{CTL}}{V_{CC}}$$

An internal DC voltage equal to:

$$V_{DC} = (1.683 \times V_{CTL}) + V_{VALLEY}$$

is compared to the oscillator voltage to produce the com-

pensated duty cycle. The transfer is set up so that when $V_{CC} = 14V$ the duty cycle will equal V_{CTL} divided by V_{REG} . For example at $V_{CC} = 14V$, $V_{REG} = 5V$ and $V_{CTL} = 2.5V$, the duty cycle would be 50% at the output. This would place a 7V average voltage across the load. If V_{CC} then drops to 10V, the IC would change the duty cycle to 70% and hence keep the average load voltage at 7V.

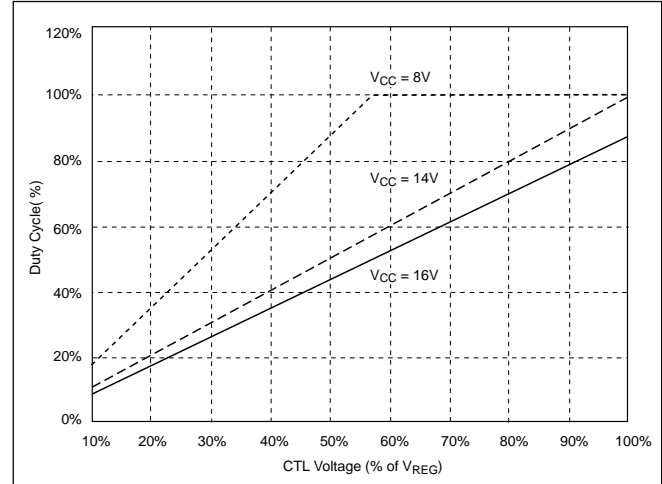


Figure 1: Voltage Compensation

5V Linear Regulator

There is a 5V, 5mA linear regulator available at the V_{REG} lead for external use. This voltage acts as a reference for many internal and external functions. It has a drop out of approximately 1.5V at room temperature.

Current Sense and Timer

The IC differentially monitors the load current on a cycle by cycle basis at the I_{SENSE+} and I_{SENSE-} leads. The differential voltage across these two leads is amplified internally and compared to the voltage at the I_{ADJ} lead. The gain, A_V is set internally and externally by the following equation:

$$A_V = \frac{V_{I(ADJ)}}{I_{SENSE+} - I_{SENSE-}} = \frac{37000}{1000 + R_{CS}}$$

The current limit (I_{LIM}) is set by the external current sense resistor (R_{SENSE}) placed across the I_{SENSE+} and I_{SENSE-} terminals and the voltage at the I_{ADJ} lead.

$$I_{LIM} = \frac{1000 + R_{CS}}{37000} \times \frac{V_{I(ADJ)}}{R_{SENSE}}$$

The R_{CS} resistors and C_{CS} components form a differential low pass filter which filters out high frequency noise generated by the switching of the external MOSFET and the associated lead noise. R_{CS} also forms an error term in the gain of the I_{LIM} equation because the I_{SENSE+} and I_{SENSE-} leads are low impedance inputs thereby creating a good current sensing amplifier. Both leads source 50 μA while the chip is in run mode. I_{ADJ} should be biased between 1V and 4V. When the current through the external MOSFET

exceeds I_{LIM} , an internal latch is set and the output pulls the gate of the MOSFET low for the remainder of the oscillator cycle (fault mode). At the start of the next cycle, the latch is reset and the IC reverts back to run mode until another fault occurs. If a number of faults occur in a given period of time, the IC “times out” and disables the MOSFET for a long period of time to let it cool off. This is accomplished by charging the C_{FLT} capacitor each time an over current condition occurs. If a cycle goes by with no overcurrent fault occurring, an even smaller amount of charge will be removed from C_{FLT} . If enough faults occur together, eventually C_{FLT} will charge up to 2.4V and the fault latch will be set. The fault latch will not be reset until C_{FLT} discharges to 0.6V. This action will continue indefinitely if the fault persists.

The off time and on time are set by the following:

$$\text{Off Time} = C_{FLT} \times \frac{2.4V - 0.6V}{4.5\mu A}$$

$$\text{On Time} = C_{FLT} \times \frac{2.4V - 0.6V}{I_{AVG}}$$

where:

$$I_{AVG} = (295.5\mu A \times DC) - [4.5\mu A \times (1 - DC)]$$

$$I_{AVG} = (300\mu A \times DC) - 4.5\mu A$$

$$DC = \text{PWM Duty Cycle}$$

Boost Switch Mode Power Supply

The CS4124 has an integrated boost mode power supply which charges the gate of the external high-side MOSFET to greater than 5V above V_{CC} . Three leads are used for voltage boost. They are Boost, PMP and SNI. The PMP lead is the collector of a darlington tied NPN power transistor. This device charges the inductor during its on time. The boost lead is the input to chip from the external reservoir capacitor. The SNI lead is the emitter of the power NPN and is connected externally to the R_{SNI} resistor.

The power supply is controlled by the oscillator. At the start of a cycle an R-S flip flop is set the internal power NPN transistor is turned on and energy begins to build up in the inductor. The R_{SNI} resistor sets the peak current of the inductor by tripping a comparator when the voltage across the resistor is 450mV. The flip flop is reset and the inductor delivers its stored energy to the load. The ripple voltage (V_{RIPPLE}) at the Boost lead is controlled by C_{BOOST} . A snubber circuit, made up of a series resistor and capacitor, is required to dampen the ringing of the inductor. A value of 4Ω is recommended for R_{SNI} .

A zener diode is needed between the boost output voltage and the battery. This will clamp the boost lead to a specified value above the battery to prevent damage to the IC. A 9 volt zener diode is recommended.

Sleep State

This device will enter into a low current mode ($< 275\mu A$) when CTL lead is brought to less than 0.5V. All functions are disabled in this mode, except for the regulator.

Inhibit

When the inhibit is greater than 2.5V the internal latch is set and the external MOSFET will be turned off for the remainder of the oscillator cycle. The latch is then reset at the start of the next cycle.

Overvoltage Shutdown

The IC will disable the output during an overvoltage event. This is a real time fault event and does not set the internal latch and therefore is independent of the oscillator timing (i.e. asynchronous). There is 325mV (typical) of hysteresis on the overvoltage function. There is no under-voltage lockout. The device will shutdown gracefully once it runs out of headroom.

Reverse Battery

The CS4124 will not survive a reverse battery condition. A series diode is required between the battery and the V_{CC} lead for reverse battery.

Load Dump

A 10Ω resistor, (R_S) is placed in series with V_{CC} to limit the current into the IC during 40V peak transient conditions.

Package Specification

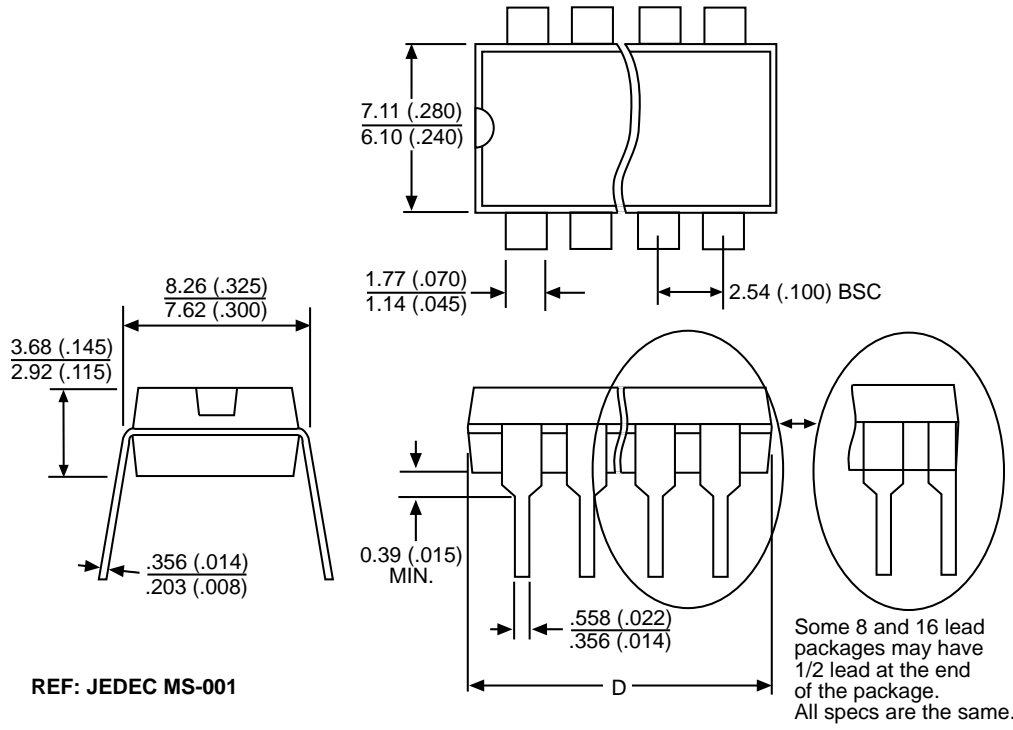
PACKAGE DIMENSIONS IN mm (INCHES)

Lead Count	D			
	Metric		English	
	Max	Min	Max	Min
16L PDIP	19.69	18.67	.775	.735

PACKAGE THERMAL DATA

Thermal Data		16 Lead PDIP	
$R_{\theta JC}$	typ	42	$^{\circ}C/W$
$R_{\theta JA}$	typ	80	$^{\circ}C/W$

Plastic DIP (N); 300 mil wide



Ordering Information

Part Number	Description
CS4124YN16	16L PDIP

Cherry Semiconductor Corporation reserves the right to make changes to the specifications without notice. Please contact Cherry Semiconductor Corporation for the latest available information.